

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	159	(mask) near25 (epitaxial) near15 (gallium near nitride or gan)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
2	BRS	L2	7	(mask) near25 (epitaxial) near15 (gallium near nitride or gan) near25 (polycrystalline)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
3	BRS	L3	8	(mask) near25 (epitaxial) near15 (gallium near nitride or gan) near25 (alloys)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
4	BRS	L4	8	(mask) near25 (epitaxial) near15 (gallium near nitride or gan) near15 (nitride near alloys)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs
5	BRS	L5	2	(substrate or wafer) near25 (epitaxial) near15 (gallium near nitride or gan) near15 (nitride near alloys)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
6	BRS	L6	1217	(substrate or wafer) near25 (epitaxial) near15 (gallium near nitride or gan)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
7	BRS	L7	5	(substrate or wafer) near25 (epitaxial) near15 (gallium near nitride or gan) near15 (polycrystalline)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
8	BRS	L8	5	(substrate or wafer) near25 (epitaxial) near15 (gallium near nitride or gan) near35 (polycrystalline)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs
9	BRS	L9	235	(substrate or wafer) near25 (epitaxial) near15 (gallium near nitride or gan) near35 (buffer)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
10	BRS	L10	1	(substrate or wafer) near25 (epitaxial) near15 (gallium near nitride near10 alloys) near35 (buffer)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	U	1	Document ID	Title
1			US 20040082150 A1	Single step pendeo-and lateral epitaxial overgrowth of group III-nitride epitaxial layers with group III-nitride buffer layer and resulting structures
2			US 20030207518 A1	Single step pendeo- and lateral epitaxial overgrowth of Group III-nitride epitaxial layers with Group III-nitride buffer layer and resulting structures
3			US 20020098693 A1	Single step pendeo- and lateral epitaxial overgrowth of group III-nitride epitaxial layers with group III-nitride buffer layer and resulting structures
4			US 20020022290 A1	Single step pendeo-and lateral epitaxial overgrowth of group III-nitride epitaxial layers with group III-nitride buffer layer and resulting structures
5			US 6812053 B1	Single step pendeo- and lateral epitaxial overgrowth of Group III-nitride epitaxial layers with Group III-nitride buffer layer and resulting structures
6			US 6803602 B2	Single step pendeo- and lateral epitaxial overgrowth of Group III-nitride epitaxial layers with Group III-nitride buffer layer and resulting structures

	U	1	Document ID	Title
7			US 6764932 B2	Single step pendeo- and lateral epitaxial overgrowth of group III-nitride epitaxial layers with group III-nitride buffer layer and resulting structures